

iscN-Channel MOSFET Transistor
TK3R3A06PL, ITK3R3A06PL
• FEATURES

- Low drain-source on-resistance:
 $R_{DS(ON)} = 2.5m\Omega$ (typ.) ($V_{GS} = 10V$)
- Enhancement mode:
 $V_{th} = 1.5$ to $2.5V$ ($V_{DS} = 10V$, $I_D = 0.7mA$)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

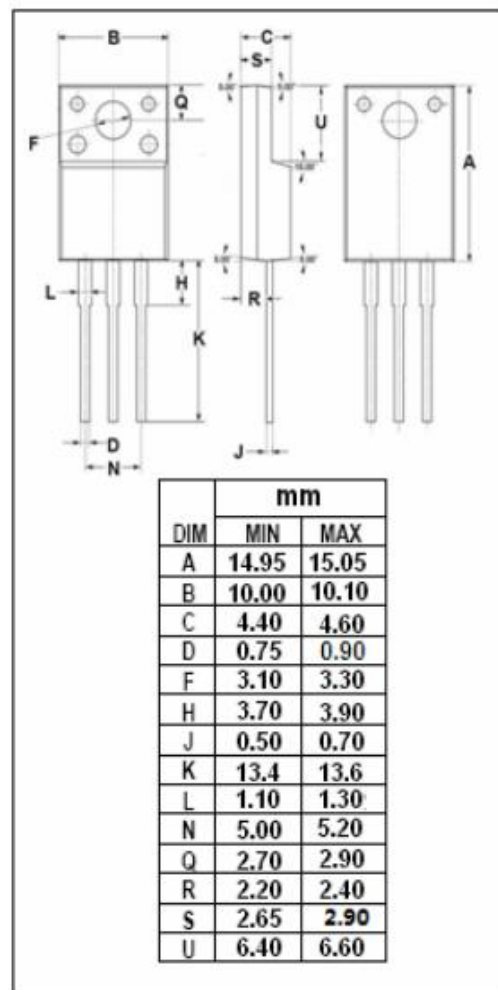
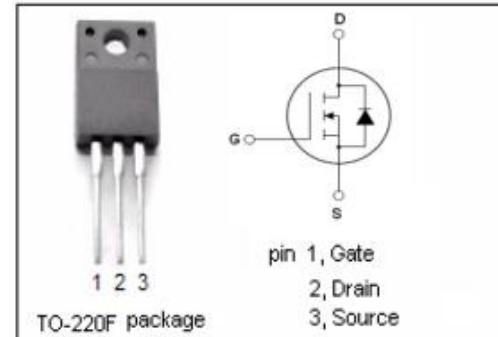
- Switching Voltage Regulators

• ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	60	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	80	A
I_{DM}	Drain Current-Single Pulsed	400	A
P_D	Total Dissipation @ $T_c = 25^\circ C$	42	W
T_j	Max. Operating Junction Temperature	175	$^\circ C$
T_{stg}	Storage Temperature	-55~175	$^\circ C$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	3.57	$^\circ C/W$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	62.5	$^\circ C/W$



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ELECTRICAL CHARACTERISTICS

 T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	60			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = 10V; I _D =0.7mA	1.5		2.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 4.5V; I _D =34A		3.3	4.9	mΩ
		V _{GS} = 10V; I _D =40A		2.5	3.3	
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 60V; V _{GS} = 0V			10	μA
V _{SDF}	Diode forward voltage	I _{DR} =80A, V _{GS} = 0 V			1.5	V

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